PCN Number: 202			230328011.2			CN Da	te:	March 30, 2023		
Title: Qualification of RF (MLA) for select B					AB as an additional Fab site option and new Assembly & Test site					
Cus	tomer	Contact:		PCN	l <u>Manager</u>	D	ept:		Quality Services	
Proposed 1 <sup>st</sup> Ship Date:			•	Sep	25, 2023		Sample requests accepted until: Apr 29, 2023*			
*Sa	mple r	requests recei	ived	afte	r April 29, 2023 wil	I not be s	uppo	rted.		
Change Type:										
$\boxtimes$	Assen	nbly Site		Assembly Process				Assembly Materials		
$\boxtimes$	⊠ Design			☐ Electrical Specification				Mechanical Specification		
$\boxtimes$	Test S	Site		Packing/Shipping/Labeling				Test Process		
	Wafer	Bump Site		☐ Wafer Bump Material				Wafer Bump Process		
			₩ Wafer Fab Materials				Wafer Fab Process			
				☐ Part number change						
	PCN Details									
Des	criptio	n of Change:								

Texas Instruments is pleased to announce the qualification of its RFAB fabrication facility as an additional Wafer Fab option in addition to new Assembly and test site (MLA) for the devices listed in the "Product Affected" section.

	Current Fa	b Site	New Fab Site			
Fab Site	Process	Wafer Diameter	Fab Site	Process	<b>Wafer Diameter</b>	
FR-BIP1	BCB8	200 mm	RFAB	LBC9	300 mm	

Construction differences and AT site options are as follows:

	FMX	MLA
Bond wire composition, diameter diameter(Cu)	Au, 0.96 mil	Cu, 0.8 mil

Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ

# **Reason for Change:**

Supply continuity

# Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

## **Impact on Environmental Ratings**

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
☑ No Change	⊠ No Change	⊠ No Change	⊠ No Change

# Changes to product identification resulting from this PCN:

# **Fab Site Information:**

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City		
FR-BIP1	TID	DEU	Freising		
RFAB	RFB	USA	Richardson		

## Die Rev:

Current	New
Die Rev [2P]	Die Rev [2P]

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City		
FMX	MEX	MEX	Aguascalientes		
MLA	MLA	MYS	KUALA LUMPUR		

Sample product shipping label (not actual product label):



2DC: 2Q; MSL '2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: LBL: 5A (L)T0:1750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812

(P) (V) 9933317 (2P) REV: (V) 9933317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

# **Product Affected:**

|--|

# Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

# LMV393-Q Refresh (Rel Data carried from the TLV9022QDRQ1) Approve Date 10-June-2022

## **Product Attributes**

Attributes	Qual Device:
Attributes	LMV393QDRQ1
Automotive Grade Level	Grade 1
Operating Temp Range (C)	-40 to 125
Product Function	Signal Chain
Wafer Fab Supplier	RFAB
Assembly Site	MLA
Package Group	SOIC
Package Designator	D
Pin Count	8

- · QBS: Qual By Similarity
- Qual Device LMV393QDRQ1 is qualified at MSL1 260C

### **Qualification Results**

# Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: <u>LMV393QDRQ1</u>
Test Group	Fest Group A - Accelerated Environment Stress Tests							
PC	A1	JEDEC J-STD-020 JESD22- A113	3	77	Preconditioning	MSL1 260C	1 Step	3/924/0
HAST	A2	JEDEC JESD22-A110	3	77	Biased HAST	130C/85%RH	96 Hours	3/231/0
AC/UHAST	А3	JEDEC JESD22- A102/JEDEC JESD22-A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	3/231/0
тс	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	3/231/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-	1/5/0
Test Group	B - Acce	elerated Lifetime Simulation Tes	ts					
HTOL	B1	JEDEC JESD22-A108	1	77	Life Test	125C	1000 Hours	3/231/0
ELFR	B2	AEC Q100-008	1	77	Early Life Failure Rate	125C	48 Hours	3/2400/0
Test Group	C - Pack	age Assembly Integrity Tests						
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0
SD	C3	JEDEC JESD22-B102	1	15	PB Solderability	>95% Lead Coverage	-	1/15/0
SD	С3	JEDEC JESD22-B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	1/15/0
PD	C4	JEDEC JESD22-B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	3/30/0
Test Group	D - Die F	abrication Reliability Tests						

EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements
Test Group	E - Elect	rical Verification Tests						
ESD	E2	AEC Q100-002	1	3	ESD HBM	-	2000 Volts	1/3/0
ESD	E3	AEC Q100-011	1	3	ESD CDM	-	500 Volts	1/3/0
LU	E4	AEC Q100-004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0
ED	E5	AEC Q100-009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	3/90/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- Room/Hot/Cold : HTOL, ED
- Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2205-066



TI Information Selective Disclosure

# Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

# Q006 Summary for 0.8 Mil PCC Wire LBC9 Al Bond Pads in MLA (Grade 1, -40/125C) Approved 23-Sep-2021

### **Product Attributes**

Attributes	Qual Device: <u>OPA2991QDRQ1</u>
Operating Temp Range	-40 to +125 C
Automotive Grade Level	Grade 1
Product Function	Signal Chain
Assembly Site	MLA
Package Type	SOIC
Package Designator	D
Ball/Lead Count	8

#### Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: OPA2991QDRQ1
Test Group A – Accelerated Environment Stress Tests							
PC	A1	-	3	22	SAM Analysis, Pre Stress	Completed	3/66/0
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Preconditioning	Level 1-260C	No fails
PC	A1	-	3	22	SAM Analysis, Post Stress	Completed	3/66/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST, 130C/85%RH	96 Hours	3/231/1 (1)
HAST	A2	JEDEC JESD22- A110	3	70	Biased HAST, 130C/85%RH	192 Hours	3/210/0
HAST	A2	-	3	1	Cross Section, Post bHAST 192 Hours	Completed	3/3/0
HAST	A2	-	3	22	SAM Analysis, Post bHAST, 192 Hours	Completed	3/66/0
HAST	A2	-	3	30	Wire Bond Shear, Post bHast, 192 Hours	Wires	3/90/0
HAST	A2	-	3	30	Bond Pull over Stitch, post bHAST, 192 Hours	Wires	3/90/0
HAST	A2	-	3	30	Bond Pull over Ball, Post bHAST, 192 Hours	Wires	3/90/0
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle, -65/150C	500 Cycles	3/231/0
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle, -65/150C	1000 Cycles	3/210/0
тс	A4	-	3	1	Cross Section, Post T/C 1000 Cycles	Completed	3/3/0
тс	A4	-	3	22	SAM Analysis, Post T/C, 1000 Cycles	Completed	3/66/0
тс	A4	-	3	30	Wire Bond Shear, Post T/C 1000 Cycles	Wires	3/90/0
тс	A4	-	3	30	Bond Pull over Stitch, Post T/C, 1000 Cycles	Wires	3/90/0
тс	A4	-	3	30	Bond Pull over Ball, Post T/C, 1000 Cycles	Wires	3/90/0
PTC	A5	JEDEC JESD22- A105	1	45	Power Temperature Cycle - 40/125C	1000 Cycles	N/A

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: <u>OPA2991QDRQ1</u>
PTC	A5	JEDEC JESD22- A105	1	44	Power Temperature Cycle - 40/125C	2000 Cycles	N/A
HTSL	A6	JEDEC JESD22- A103	3	45	High Temp Storage Bake 150C	1000 Hours	3/135/0
HTSL	A6	JEDEC JESD22- A103	3	44	High Temp Storage Bake 150C	2000 Hours	3/132/0
HTSL	A6	-	3	1	Cross Section, Post HTSL 2000 Hours	Completed	3/3/0
WBS	C1	AEC Q100-001	3	30	Wire Bond Shear, Cpk>1.67	Wires	3/90/0
WBP	C2	MIL-STD883 Method 2011	3	30	Bond Pull over Ball, Cpk >1.67	Wires	3/90/0

A1 (PC): Preconditioning:
Performed for THB, Biased HAST, AC, uHAST & TC samples, as applicable

Ambient Operating Temperature by Automotive Grade Level:
Grade 0 (or E): -40C to +150C
Grade 1 (or Q): -40C to +125C
Grade 2 (or T): -40C to +105C Grade 3 (or I): -40C to +85C

### E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Note (1): HAST fail due to corrosion from foreign material.

Green/Pb-free Status:
Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20201209-137461

ZVEI IDs: SEM-PW-02, SEM-PW-09, SEM-PW-13, SEM-PA-08, SEM-PA-18, SEM-TF-01

For questions regarding this notice, e-mails can be sent to the contact shown below or your local Field Sales Representative.

Location	E-Mail			
WW Change Management Team	PCN ww admin team@list.ti.com			

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